

TDS:EMIC

拓 電 半 導 體

自主封測 品質把控 售後保障

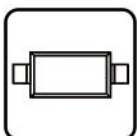
WEB | WWW.TDSEMIC.COM



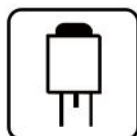
電源管理



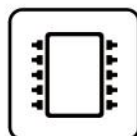
顯示驅動



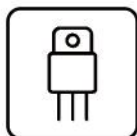
二三極管



LDO穩壓器



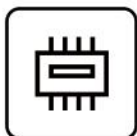
觸摸芯片



MOS管



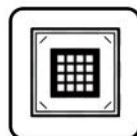
運算放大器



存儲芯片



MCU



串口通信

LESD5D5.0CT1G

產品規格說明書

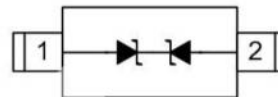
Features

- ◇ 70W (8/20 μ s) Peak Pulse Power
- ◇ Low Capacitance ESD Protection
- ◇ SOD-523 Package
- ◇ RoHS Compliant
- ◇ Matte Tin Lead finish (Pb-Free)
- ◇ Protect One High Speed Data Line
- ◇ Meet IEC61000-4-2 Level 4:
 - Contact Discharge > 8kV
 - Air Discharge > 15kV

Circuit Diagram



PIN Diagram



Applications

- ◇ Communication System
- ◇ Portable Instrumentation
- ◇ Audio and Video Equipment
- ◇ Computers and Peripherals
- ◇ USB 1.1, USB 1.0 Ports

Ordering information

Device	Package	Reel Size	Qty / Reel
LESD5D5.0CT1G	SOD-523	7 inch	3000

Maximum Ratings (Ta = 25°C)

Symbol	Parameter	Value	Unit
PPK	Peak Pulse Power	55	W
IPP	Peak Pulse Current	5	A
VESD (Contact)	Contact ESD Voltage per IEC61000-4-2	8	kV
VESD (Air)	Air ESD Voltage per IEC61000-4-2	15	kV
TJ	Junction Temperature	-55 to +150	°C
TSTG	Storage Temperature	-55 to +150	°C

Electrical Characteristics (Ta = 25°C)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
VRWM	Reverse Working Peak Voltage				5	V
VBR	Reverse Breakdown Voltage	IT = 1mA	5.7		9	V
IR	Reverse Leakage Current	VRWM = 5V			0.1	μA
VC	Clamping Voltage	IPP = 4.5A (8/20μs)			12	V
VC	Clamping Voltage	IPP = 5A (8/20 μs)			13	V
CJ	Capacitance	VR = 0V, f = 1MHz			13	pF

PACKAGE OUTLINE

SOD-523

单位: mm

